

Continental Device India Limited

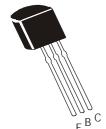
An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company





NPN SILICON PLANAR EPITAXIAL SWITCHING TRANSISTORS

2N3903 / 2N3904



TO-92
Plastic Package
For Lead Free Parts, Device
Part # will be Prefixed with
"T"

General Purpose Switching And Amplifier Applications

ABSOLUTE MAXIMUM RATINGS (T_a=25°C)

DESCRIPTION	SYMBOL	VALUE	UNITS
Collector Emitter Voltage	V _{CEO}	40	V
Collector Base Voltage	V _{CBO}	60	V
Emitter Base Voltage	V_{EBO}	6.0	V
Collector Current Continuous	I _C	200	mA
Power Dissipation at T _a =25°C	P _D	625	mW
Derate Above 25°C		5.0	mW/ºC
Power Dissipation at T _c =25°C	P _D	1.5	W
Derate Above 25°C		12	mW/ºC
Operating and Storage Junction Temperature Range	T _j , T _{stg}	-55 to +150	°C

THERMAL RESISTANCE

Junction to Case	R _{th (j-c)}	83.3	°C/W
Junction to Ambient in free air	R _{th (j-a)}	200	°C/W

ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	2N3903	2N3904	UNITS
Collector Emitter Voltage	V_{CEO}	$I_C=1$ mA, $I_B=0$	>40	>40	V
Collector Base Voltage	V_{CBO}	I _C =10μΑ. I _E =0	>60	>60	V
Emitter Base Voltage	V_{EBO}	$I_{E}=10\mu A, I_{C}=0$	>6.0	>6.0	V
Base Cut Off Current	I_{BL}	$V_{CE}=30V, V_{EB}=3V$	< 50	< 50	nA
Collector Cut Off Current	I _{CEX}	V_{CE} =30V, V_{EB} =3V	< 50	< 50	nA
DC Current Gain	*h _{FE}	$I_C=0.1$ mA, $V_{CE}=1$ V	>20	>40	
		$I_C=1$ mA, $V_{CE}=1$ V	>35	>70	
		$I_C=10mA, V_{CE}=1V$	50-150	100-300	
		$I_C=50$ mA, $V_{CE}=1$ V	>30	>60	
		$I_C=100$ mA, $V_{CE}=1$ V	>15	>30	
Collector Emitter Saturation Voltage	*V _{CE (sat)}	I _C =10mA, I _B =1mA	< 0.2	< 0.2	V
		$I_C=50$ mA, $I_B=5$ mA	< 0.3	< 0.3	V
Base Emitter Saturation Voltage	*V _{BE (sat)}	I _C =10mA, I _B =1mA	0.65 - 0.85	0.65 - 0.85	V
		$I_C=50$ mA, $I_B=5$ mA	< 0.95	< 0.95	V

*Pulse Condition: =300ms, Duty Cycle=2%

2N3903_3904Rev_1 240206E

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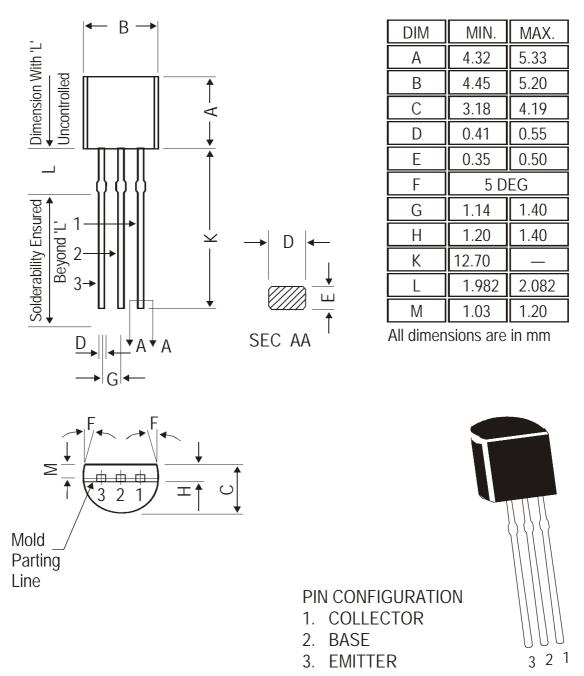
ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

SMALL SIGNAL CHARACTERISTICS

DESCRIPTION	SYMBOL	TEST CONDITION	2N3903	2N3904	UNITS
Transistors Frequency	f⊤	I _C =10mA, V _{CE} =20V, f=100MHz	>250	>300	MHz
Output Capacitance	C _{ob}	V_{CB} =5V, I_E =0, f=1MHz	pF		
Input Capacitance	C _{ib}	V _{EB} =0.5V, I _C =0, f=1MHz	< 8.0	< 8.0	pF
		ALL f=1kHz			
Small Signal Current Gain	h _{fe}	$I_C=1$ mA, $V_{CE}=10$ V	50 - 200	100 - 400	
Input Inpedence	h _{ie}	$I_C=1$ mA, $V_{CE}=10$ V	1.0 - 8.0	1.0 -10	kΩ
Voltage Feedback Ratio	h _{re}	$I_C=1$ mA, $V_{CE}=10$ V	0.1 - 5.0	0.5 - 8	x10 ⁻⁴
Out put Adimttance	h _{oe}	I _C =1mA, V _{CE} =10V	1.0 - 40	1.0 - 40	μmhos
Noise Figure	NF	I_C =100μA, V_{CE} =5V, f=1KHz, R_S =1K Ω	< 6.0	< 5.0	dB
SWITCHING Time					
Delay time	t _d	V_{CC} =3V, V_{BE} =0.5V	< 35	< 35	ns
Rise time	t _r	$I_C=10$ mA, $I_{B1}=1$ mA	< 35	< 35	ns
Storage time	t _s	$V_{CC}=3V$, $I_{C}=10mA$	< 175	< 200	ns
Fall time	t _f	$I_{B1}=1_{B2}=1$ mA	< 50	< 50	ns

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TO-92 Plastic Package



The TO-92 Package, Tape and Ammo Pack Drawings are correct as on the date of issue/revision of this Data Sheet.

The currently valid dimensions and information, may please be confirmed from the TO-92 Drawing in the Packages and

Packing Details

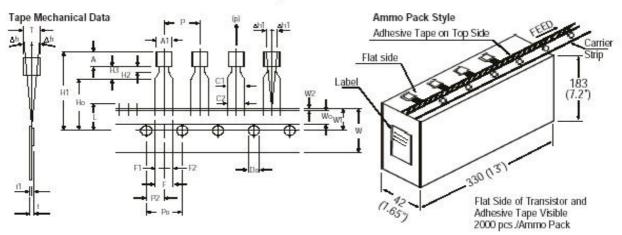
Packing Section of the Product Catalogue.

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size Oty		Gr Wt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs

TO-92 Plastic Package For Lead Free Parts, Device

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TO-92 Tape and Ammo Pack



All dimensions are in mm

		SPECIFICATION						
ITEM	SYMBOL	MIN.	NOM.	MAX.	TOL.	1		
BODY WIDTH	A1	4.45		5.20		NOTES		
BODY HEIGHT	Α	4.32		5.33		Maximum alignment deviation b		
BODY THICKNESS	T	3.18		4.19		leads will not to be greater than		
PITCH OF COMPONENT	Р		12.7		± 1.0	2. Maximum non-cumulative varia		
*1FEED HOLE PITCH	Po		12.7		± 0.3	between tape feed holes shall r		
*2 FEED HOLE CENTRE TO COMPONENT CENTRE	P2		6.35		± 0.4	exceed 1 mm in 20 pitches. 3. Holddown tape will not exceed i		
DISTANCE BETWEEN OUTER LEADS	F		5.08		+ 0.6	the edge(s) of carrier tape and t shall be no exposure of adhesiv		
*3 COMPONENT ALIGNMENT SIDE VIEW	Δh		0	1.0		4. There will be no more than three		
*4 COMPONENT ALIGNMENT FRONT VIEW	∆h1		0	1.3		consecutive missing componen		
TAPE WIDTH	W		18	9000	± 0.5	tape.		
HOLD-DOWN TAPE WIDTH	Wo		6		± 0.2	A tape trailer, having at least thr		
HOLE POSITION	W1		9		+ 0.7	holes are provided after the last component in a tape.		
HOLD-DOWN TAPE POSITION	W2	0.0		0.7		6. Splices should not interfere with		
LEAD WIRE CLINCH HEIGHT	Ho	N. 60 (100 (100 (100 (100 (100 (100 (100 (16	11610334	± 0.5	sprocket feed holes.		
COMPONENT HEIGHT	H1		10000	24.0				
LENGTH OF SNIPPED LEADS	Ti l			11.0				
FEED HOLE DIAMETER	Do		4		± 0.2	REMARKS		
*5 TOTAL TAPE THICKNESS	t			1.2				
LEAD - TO - LEAD DISTANCE	F1, F2	2.40		2.70		*1 Cumulative pitch error 1.0 mm/.		
STAND OFF	H2	0.45		1.45	- 0.1	*2 To be measured at bottom of cl		
CLINCH HEIGHT	H3	0.40		3.0		*3 At top of body		
LEAD PARALLELISM	C1 - C2			0.22		*4 At top of body		
PULL - OUT FORCE	(p)	6N		8.755.755		*5 t1 0.3 – 0.6 mm		

- between n 0.2mm.
- ation
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- √20 pitch
- clinch

Component Disposal Instructions

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Customer Notes 2N3903 / 2N3904

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Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered Trademark of
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